

Alexander Chroneos

List of Publications by Year in Descending Order

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

318
papers

7,086
citations

49
h-index

66
g-index

331
ext. papers

7,994
ext. citations

3.5
avg, IF

6.55
L-index

#	Paper	IF	Citations
318	Vapor-Liquid-Solid growth and properties of one dimensional PbO and PbO/SnO ₂ nanowires. <i>Materials Advances</i> , 2022 , 3, 1695-1702	3.3	0
317	Theoretical investigation of nitrogen-vacancy defects in silicon. <i>AIP Advances</i> , 2022 , 12, 025112	1.5	0
316	Li-diffusion pathways in Zr ₂ CO ₂ and Zr ₂ CS ₂ MXenes using the Bond Valence Sum model. <i>Computational Materials Science</i> , 2022 , 201, 110868	3.2	1
315	Nitrogen-vacancy defects in germanium. <i>AIP Advances</i> , 2022 , 12, 045110	1.5	0
314	Optical response, lithiation and charge transfer in Sn-based 211 MAX phases with electron localization function. <i>Journal of Materials Research and Technology</i> , 2022 , 18, 2470-2479	5.5	0
313	Mg-ion diffusion on the surface of Ti ₃ C ₂ S ₂ MXene. <i>Journal of Physics and Chemistry of Solids</i> , 2022 , 166, 110713	3.9	0
312	Influence of high pressure on the temperature dependence of electrical resistivity of Y _{1-x} Pr _x Ba ₂ Cu ₃ O _{7-δ} Single crystals. <i>Solid State Communications</i> , 2021 , 327, 114205	1.6	1
311	Preparation of hydrogen, fluorine and chlorine doped and co-doped titanium dioxide photocatalysts: a theoretical and experimental approach. <i>Scientific Reports</i> , 2021 , 11, 5700	4.9	5
310	Influence of Uniform Compression on the Temperature Dependence of the Pseudogap of Medium-Praseodymium-Doped Y _{1-x} Pr _x Ba ₂ Cu ₃ O _{7-δ} Single Crystals. <i>Journal of Low Temperature Physics</i> , 2021 , 203, 430-436	1.3	2
309	Effect of hydrogen on the electrical resistance of NbSe ₂ in a wide temperature range. <i>Journal of Materials Science: Materials in Electronics</i> , 2021 , 32, 13588-13593	2.1	1
308	Defects, diffusion and dopants in the ceramic mineral Lime- Feldspar. <i>Journal of Asian Ceramic Societies</i> , 2021 , 9, 570-577	2.4	2
307	Defects, diffusion, dopants and encapsulation of Na in NaZr ₂ (PO ₄) ₃ . <i>Materialia</i> , 2021 , 16, 101039	3.2	0
306	Defect and dopant properties in CaMnO ₃ . <i>AIP Advances</i> , 2021 , 11, 055106	1.5	1
305	A high-entropy manganite in an ordered nanocomposite for long-term application in solid oxide cells. <i>Nature Communications</i> , 2021 , 12, 2660	17.4	15
304	Ru-Doped Single Walled Carbon Nanotubes as Sensors for SO ₂ and H ₂ S Detection. <i>Chemosensors</i> , 2021 , 9, 120	4	4
303	Substitutional carbon-dioxygen center in irradiated silicon. <i>Materials Science in Semiconductor Processing</i> , 2021 , 127, 105661	4.3	1
302	One-dimensional yttrium silicide electride (Y ₅ Si ₃ e) for encapsulation of volatile fission products. <i>Journal of Applied Physics</i> , 2021 , 129, 245105	2.5	1

301	Impact of oxygen on gallium doped germanium. <i>AIP Advances</i> , 2021 , 11, 065122	1.5	1
300	Impact of boron and indium doping on the structural, electronic and optical properties of SnO. <i>Scientific Reports</i> , 2021 , 11, 13031	4.9	6
299	Defect Properties and Lithium Incorporation in Li ₂ ZrO ₃ . <i>Energies</i> , 2021 , 14, 3963	3.1	4
298	Interstitial lithium doping in SrTiO ₃ . <i>AIP Advances</i> , 2021 , 11, 075029	1.5	0
297	Defects, diffusion and dopants in LiSnO. <i>Heliyon</i> , 2021 , 7, e07460	3.6	0
296	Insights into the physical properties of a new 211 MAX phase Nb ₂ CuC. <i>Journal of Physics and Chemistry of Solids</i> , 2021 , 149, 109759	3.9	13
295	Robust Inorganic Hole Transport Materials for Organic and Perovskite Solar Cells: Insights into Materials Electronic Properties and Device Performance. <i>Solar Rrl</i> , 2021 , 5, 2000555	7.1	13
294	Defect Processes in Halogen Doped SnO ₂ . <i>Applied Sciences (Switzerland)</i> , 2021 , 11, 551	2.6	4
293	Effects of Al substitution by Si in TiAlC nanolaminate. <i>Scientific Reports</i> , 2021 , 11, 3410	4.9	6
292	Structural, Electronic, and Optical Properties of Group 6 Doped Anatase TiO ₂ : A Theoretical Approach. <i>Applied Sciences (Switzerland)</i> , 2021 , 11, 1657	2.6	0
291	Behavior of Li-ion on the surface of Ti ₃ C ₂ T _x (T = O, S, Se, F, Cl, Br) MXene: Diffusion barrier and conductive pathways. <i>Journal of Applied Physics</i> , 2021 , 130, 095101	2.5	2
290	Oxygen migration in doped BaGdInO ₄ . <i>Solid State Ionics</i> , 2021 , 369, 115729	3.3	
289	Self-diffusion in garnet-type LiLaZrO solid electrolytes. <i>Scientific Reports</i> , 2021 , 11, 451	4.9	8
288	Chemically stable new MAX phase VS _n C: a damage and radiation tolerant TBC material.. <i>RSC Advances</i> , 2020 , 10, 43783-43798	3.7	12
287	Atomic structure and electronic properties of hydrogenated X (=C, Si, Ge, and Sn) doped TiO ₂ : A theoretical perspective. <i>AIP Advances</i> , 2020 , 10, 115316	1.5	1
286	The Interstitial CarbonDioxygen Center in Irradiated Silicon. <i>Crystals</i> , 2020 , 10, 1005	2.3	2
285	A perspective on MXenes: Their synthesis, properties, and recent applications. <i>Journal of Applied Physics</i> , 2020 , 128, 170902	2.5	30
284	Electronegativity and doping in SiGe alloys. <i>Scientific Reports</i> , 2020 , 10, 7459	4.9	4

283	Self-Diffusion in Perovskite and Perovskite Related Oxides: Insights from Modelling. <i>Applied Sciences (Switzerland)</i> , 2020 , 10, 2286	2.6	3
282	Electron irradiation and annealing effects on the pseudogap in optimally doped YBCO single crystals. <i>Modern Physics Letters B</i> , 2020 , 34, 2050151	1.6	
281	Defects and Dopants in CaFeSi ₂ O ₆ : Classical and DFT Simulations. <i>Energies</i> , 2020 , 13, 1285	3.1	6
280	Structural, defect, transport and dopant properties of AgNbO ₃ . <i>ChemNanoMat</i> , 2020 , 6, 1337-1345	3.5	3
279	Encapsulation and substitution of Fe in C12A7 (12CaO·7Al ₂ O ₃). <i>AIP Advances</i> , 2020 , 10, 015242	1.5	3
278	Computer modeling investigation of MgV ₂ O ₄ for Mg-ion batteries. <i>Journal of Applied Physics</i> , 2020 , 127, 035106	2.5	2
277	Lithium Storage in Nanoporous Complex Oxide 12CaO·Al ₂ O ₃ (C12A7). <i>Energies</i> , 2020 , 13, 1547	3.1	4
276	Fundamental Point Defect Properties in Ceramics 2020 , 50-73		
275	The Ci(Sil)n defect in neutron-irradiated silicon. <i>Journal of Materials Science: Materials in Electronics</i> , 2020 , 31, 930-934	2.1	1
274	Mayenite Electrides and Their Doped Forms for Oxygen Reduction Reaction in Solid Oxide Fuel Cells. <i>Energies</i> , 2020 , 13, 4978	3.1	
273	Elastic behaviour and radiation tolerance in Nb-based 211 MAX phases. <i>Materials Today Communications</i> , 2020 , 25, 101499	2.5	7
272	Atomic-scale studies of garnet-type Mg ₃ Fe ₂ Si ₃ O ₁₂ : Defect chemistry, diffusion and dopant properties. <i>Journal of Power Sources Advances</i> , 2020 , 3, 100016	3.3	
271	Defects, Diffusion and Dopants in Sillimanite. <i>Minerals (Basel, Switzerland)</i> , 2020 , 10, 857	2.4	
270	Composition variation and electron irradiation effects on the fluctuation conductivity in Y _{1-x} Pr _x Ba ₂ Cu ₃ O _{7-δ} single crystals. <i>Journal of Materials Science: Materials in Electronics</i> , 2020 , 31, 19429-19436	2.1	1
269	Electronic properties of the SnPbO alloy and band alignment of the SnO/PbO system: a DFT study. <i>Scientific Reports</i> , 2020 , 10, 16828	4.9	2
268	Defects and Calcium Diffusion in Wollastonite. <i>Chemistry</i> , 2020 , 2, 937-946	2.1	
267	Defect, transport, and dopant properties of andradite garnet Ca ₃ Fe ₂ Si ₃ O ₁₂ . <i>AIP Advances</i> , 2020 , 10, 075004	1.5	3
266	Encapsulation of volatile fission products in a two-dimensional dicalcium nitride electride. <i>Journal of Applied Physics</i> , 2020 , 128, 045112	2.5	1

265	Hydrogen Adsorption on Ru-Encapsulated, -Doped and -Supported Surfaces of C60. <i>Surfaces</i> , 2020 , 3, 408-422	2.9	2
264	Influence of defects on anisotropy of electrical resistivity in (hbox {YBa}_2hbox {Cu}_3hbox {O}_{7-delta}). <i>Journal of Materials Science: Materials in Electronics</i> , 2020 , 31, 7708-7714	2.1	2
263	Defects, Diffusion, and Dopants in LiTiO: Atomistic Simulation Study. <i>Materials</i> , 2019 , 12,	3.5	10
262	Defect, Diffusion and Dopant Properties of NaNiO2: Atomistic Simulation Study. <i>Energies</i> , 2019 , 12, 3094	3.1	9
261	Lithium Doping of ZnO for High Efficiency and Stability Fullerene and Non-fullerene Organic Solar Cells. <i>ACS Applied Energy Materials</i> , 2019 , 2, 1663-1675	6.1	30
260	Grain Boundaries: Engineering Transport in Manganites by Tuning Local Nonstoichiometry in Grain Boundaries (Adv. Mater. 4/2019). <i>Advanced Materials</i> , 2019 , 31, 1970026	2.4	2
259	Encapsulation of cadmium telluride nanocrystals within single walled carbon nanotubes. <i>Inorganica Chimica Acta</i> , 2019 , 488, 246-254	2.7	5
258	Defect Chemistry and Li-ion Diffusion in LiRuO. <i>Scientific Reports</i> , 2019 , 9, 550	4.9	27
257	Diffusion and Dopant Activation in Germanium: Insights from Recent Experimental and Theoretical Results. <i>Applied Sciences (Switzerland)</i> , 2019 , 9, 2454	2.6	7
256	Effect of annealing on a pseudogap state in untwinned YBaCuO single crystals. <i>Scientific Reports</i> , 2019 , 9, 9274	4.9	41
255	Defect Chemistry and Na-Ion Diffusion in NaFe(PO) Cathode Material. <i>Materials</i> , 2019 , 12,	3.5	12
254	Technetium Encapsulation by A Nanoporous Complex Oxide 12CaO·7AlO (C12A7). <i>Nanomaterials</i> , 2019 , 9,	5.4	9
253	Defect Process, Dopant Behaviour and Li Ion Mobility in the Li2MnO3 Cathode Material. <i>Energies</i> , 2019 , 12, 1329	3.1	10
252	Encapsulation of heavy metals by a nanoporous complex oxide 12CaO·7Al2O3. <i>Journal of Applied Physics</i> , 2019 , 125, 165103	2.5	6
251	Defects, dopants and Mg diffusion in MgTiO. <i>Scientific Reports</i> , 2019 , 9, 4394	4.9	44
250	Defects, dopants and Li-ion diffusion in Li2SiO3. <i>Solid State Ionics</i> , 2019 , 335, 61-66	3.3	25
249	The Effect of the Precursor Solution Pretreatment on the Properties and Microstructure of the SCS Final Nanomaterials. <i>Applied Sciences (Switzerland)</i> , 2019 , 9, 1200	2.6	2
248	Na3V(PO4)2 cathode material for Na ion batteries: Defects, dopants and Na diffusion. <i>Solid State Ionics</i> , 2019 , 336, 75-79	3.3	15

247	Impact of local composition on the energetics of E-centres in SiGe alloys. <i>Scientific Reports</i> , 2019 , 9, 10849	4.9	3
246	Atomistic Simulations of the Defect Chemistry and Self-Diffusion of Li-ion in LiAlO ₂ . <i>Energies</i> , 2019 , 12, 2895	3.1	5
245	Defect Chemistry, Sodium Diffusion and Doping Behaviour in NaFeO Polymorphs as Cathode Materials for Na-Ion Batteries: A Computational Study. <i>Materials</i> , 2019 , 12,	3.5	4
244	Theoretical Modeling of Defects, Dopants, and Diffusion in the Mineral Ilmenite. <i>Minerals (Basel, Switzerland)</i> , 2019 , 9, 610	2.4	4
243	The encapsulation selectivity for anionic fission products imparted by an electride. <i>Scientific Reports</i> , 2019 , 9, 13612	4.9	12
242	Mg ₆ MnO ₈ as a Magnesium-Ion Battery Material: Defects, Dopants and Mg-Ion Transport. <i>Energies</i> , 2019 , 12, 3213	3.1	8
241	A Computational Study of Defects, Li-Ion Migration and Dopants in Li ₂ ZnSiO ₄ Polymorphs. <i>Crystals</i> , 2019 , 9, 563	2.3	5
240	Stability of Coinage Metals Interacting with C. <i>Nanomaterials</i> , 2019 , 9,	5.4	3
239	Defects and dopant properties of LiV(PO). <i>Scientific Reports</i> , 2019 , 9, 333	4.9	29
238	Defects, Lithium Mobility and Tetravalent Dopants in the LiNbO Cathode Material. <i>Scientific Reports</i> , 2019 , 9, 2192	4.9	21
237	Cadmium trapping by C ₆₀ and B-, Si-, and N-doped C ₆₀ . <i>Journal of Applied Physics</i> , 2019 , 125, 054302	2.5	6
236	Peculiarities of pseudogap in YPrBaCuO single crystals under pressure up to 1.7 GPa. <i>Scientific Reports</i> , 2019 , 9, 20424	4.9	27
235	Defect processes in F and Cl doped anatase TiO. <i>Scientific Reports</i> , 2019 , 9, 19970	4.9	18
234	Effects of Precursor Concentration in Solvent and Nanomaterials Room Temperature Aging on the Growth Morphology and Surface Characteristics of Ni ₂ NiO Nanocatalysts Produced by Dendrites Combustion during SCS. <i>Applied Sciences (Switzerland)</i> , 2019 , 9, 4925	2.6	5
233	312 MAX Phases: Elastic Properties and Lithiation. <i>Materials</i> , 2019 , 12,	3.5	13
232	Li ₃ SbO ₄ lithium-ion battery material: Defects, lithium ion diffusion and tetravalent dopants. <i>Materials Chemistry and Physics</i> , 2019 , 225, 34-41	4.4	20
231	Engineering Transport in Manganites by Tuning Local Nonstoichiometry in Grain Boundaries. <i>Advanced Materials</i> , 2019 , 31, e1805360	2.4	16
230	Learning Driver Braking Behavior Using Smartphones, Neural Networks and the Sliding Correlation Coefficient: Road Anomaly Case Study. <i>IEEE Transactions on Intelligent Transportation Systems</i> , 2019 , 20, 65-74	6.1	23

229	Effect of electron irradiation on the fluctuation conductivity in YBa ₂ Cu ₃ O ₇ single crystals. <i>Journal of Materials Science: Materials in Electronics</i> , 2018 , 29, 7725-7729	2.1	7
228	Lithium diffusion in LiFeO. <i>Scientific Reports</i> , 2018 , 8, 5832	4.9	28
227	Intrinsic defect processes and elastic properties of Ti ₃ AC ₂ (A = Al, Si, Ga, Ge, In, Sn) MAX phases. <i>Journal of Applied Physics</i> , 2018 , 123, 025103	2.5	27
226	Enhanced oxygen diffusion in nano-structured ceria. <i>Journal of Materials Science: Materials in Electronics</i> , 2018 , 29, 4743-4748	2.1	3
225	Parametric Optimisation of Solution Combustion Synthesis Catalysts and Their Application for the Aqueous Hydrogenation of Maleic Acid. <i>Catalysis Letters</i> , 2018 , 148, 764-778	2.8	6
224	The COV defect in neutron irradiated silicon: An infrared spectroscopy study. <i>Materials Science in Semiconductor Processing</i> , 2018 , 75, 283-287	4.3	1
223	Migration of sodium and lithium interstitials in anatase TiO ₂ . <i>Solid State Ionics</i> , 2018 , 315, 40-43	3.3	8
222	Isovalent doping and the CiOi defect in germanium. <i>Journal of Materials Science: Materials in Electronics</i> , 2018 , 29, 4261-4265	2.1	1
221	Probabilistic kernel machines for predictive monitoring of weld residual stress in energy systems. <i>Engineering Applications of Artificial Intelligence</i> , 2018 , 71, 138-154	7.2	7
220	Physical properties and defect processes of M ₃ SnC ₂ (M = Ti, Zr, Hf) MAX phases: Effect of M-elements. <i>Journal of Alloys and Compounds</i> , 2018 , 748, 804-813	5.7	33
219	Defect pair formation in fluorine and nitrogen codoped TiO ₂ . <i>Journal of Applied Physics</i> , 2018 , 123, 161510	1.0	7
218	The CC(Si) Defect in Silicon from a Density Functional Theory Perspective. <i>Materials</i> , 2018 , 11,	3.5	4
217	Defects and lithium migration in LiCuO. <i>Scientific Reports</i> , 2018 , 8, 6754	4.9	26
216	A roadmap of strain in doped anatase TiO. <i>Scientific Reports</i> , 2018 , 8, 12790	4.9	18
215	LiSnO as a Cathode Material for Lithium-ion Batteries: Defects, Lithium Ion Diffusion and Dopants. <i>Scientific Reports</i> , 2018 , 8, 12621	4.9	28
214	Review of Recent Studies on Solution Combustion Synthesis of Nanostructured Catalysts. <i>Advanced Engineering Materials</i> , 2018 , 20, 1800047	3.5	48
213	Ab initio modeling of MAX phase solid solutions using the special quasirandom structure approach. <i>Physical Chemistry Chemical Physics</i> , 2018 , 20, 1173-1180	3.6	10
212	Thermodynamic modelling of fast dopant diffusion in Si. <i>Journal of Applied Physics</i> , 2018 , 123, 161527	2.5	4

211	Defect process and lithium diffusion in Li ₂ TiO ₃ . <i>Solid State Ionics</i> , 2018 , 327, 93-98	3.3	35
210	Influence of Preheating Temperature on Solution Combustion Synthesis of Ni ₃ NiO Nanocomposites: Mathematical Model and Experiment. <i>International Journal of Self-Propagating High-Temperature Synthesis</i> , 2018 , 27, 207-215	0.7	6
209	Defects, Dopants and Sodium Mobility in NaMnSiO. <i>Scientific Reports</i> , 2018 , 8, 14669	4.9	29
208	Defects, Dopants and Lithium Mobility in Li V (P O) (PO). <i>Scientific Reports</i> , 2018 , 8, 8140	4.9	21
207	Mg diffusion in Si on a thermodynamic basis. <i>Journal of Materials Science: Materials in Electronics</i> , 2018 , 29, 12022-12027	2.1	7
206	Solution combustion synthesis of nano-catalysts with a hierarchical structure. <i>Journal of Catalysis</i> , 2018 , 364, 112-124	7.3	23
205	Charge and heat transfer of the Ti ₃ AlC ₂ MAX phase. <i>Journal of Materials Science: Materials in Electronics</i> , 2018 , 29, 11478-11481	2.1	5
204	Computational study of energy materials 2018 , 263-281		
203	Influence of atomic structure on the nano-nickel-based catalyst activity produced by solution combustion synthesis in the hydrogenation of maleic acid. <i>Journal of Catalysis</i> , 2017 , 348, 9-21	7.3	15
202	Intrinsic Defects and H Doping in WO. <i>Scientific Reports</i> , 2017 , 7, 40882	4.9	43
201	IR studies of the oxygen and carbon precipitation processes in electron irradiated tin-doped silicon. <i>Journal of Materials Science: Materials in Electronics</i> , 2017 , 28, 10298-10312	2.1	2
200	O vacancy formation in (Pr/Gd)BaCoO and the role of antisite defects. <i>Physical Chemistry Chemical Physics</i> , 2017 , 19, 11455-11459	3.6	1
199	Different diffusion mechanisms of oxygen in ReBa ₂ Cu ₃ O _{7-δ} (Re = Y, Ho) single crystals. <i>Physica C: Superconductivity and Its Applications</i> , 2017 , 536, 26-29	1.3	14
198	Diffusion of the superconducting transition in HTSC. <i>Journal of Materials Science: Materials in Electronics</i> , 2017 , 28, 10862-10865	2.1	
197	Detecting anomalies in time series data via a deep learning algorithm combining wavelets, neural networks and Hilbert transform. <i>Expert Systems With Applications</i> , 2017 , 85, 292-304	7.8	56
196	Synthesis and physical properties of (Zr _{1-x} Ti _x) ₃ AlC ₂ MAX phases. <i>Journal of the American Ceramic Society</i> , 2017 , 100, 3393-3401	3.8	49
195	Effect of Hafnium Impurities on the Magnetoresistance of (YBa ₂ Cu ₃ O _{7-δ}). <i>Journal of Low Temperature Physics</i> , 2017 , 186, 285-293	1.3	1
194	Elastic and thermodynamic properties of new (Zr _{3-x} Ti _x)AlC ₂ MAX-phase solid solutions. <i>Computational Materials Science</i> , 2017 , 137, 318-326	3.2	87

193	The CiO _i (Si _l) ₂ defect in silicon: density functional theory calculations. <i>Journal of Materials Science: Materials in Electronics</i> , 2017 , 28, 10295-10297	2.1	6
192	Defect processes of M ₃ AlC ₂ (M = V, Zr, Ta, Ti) MAX phases. <i>Solid State Communications</i> , 2017 , 261, 54-56	1.6	6
191	Tin diffusion in germanium: a thermodynamic approach. <i>Journal of Materials Science: Materials in Electronics</i> , 2017 , 28, 9936-9940	2.1	4
190	Experimental synthesis and density functional theory investigation of radiation tolerance of Zr ₃ (Al _{1-x} Si _x)C ₂ MAX phases. <i>Journal of the American Ceramic Society</i> , 2017 , 100, 1377-1387	3.8	33
189	Modelling solid solutions with cluster expansion, special quasirandom structures, and thermodynamic approaches. <i>Applied Physics Reviews</i> , 2017 , 4, 041301	17.3	15
188	Diffusion coalescence in Ba ₂ Cu ₃ O ₇ single crystals under the application of hydrostatic pressure. <i>Materials Research Express</i> , 2017 , 4, 096001	1.7	3
187	Diffusion in energy materials: Governing dynamics from atomistic modelling. <i>Applied Physics Reviews</i> , 2017 , 4, 031305	17.3	15
186	Stress-enhanced lithiation in MAX compounds for battery applications. <i>Applied Materials Today</i> , 2017 , 9, 192-195	6.6	8
185	Defect processes in Li ₂ ZrO ₃ : insights from atomistic modelling. <i>Journal of Materials Science: Materials in Electronics</i> , 2017 , 28, 11789-11793	2.1	5
184	Composition and temperature dependence of self-diffusion in Si Ge alloys. <i>Scientific Reports</i> , 2017 , 7, 1374	4.9	20
183	Impact of isovalent doping on the formation of the C i O i (Si I) n defects in silicon. <i>Solid State Communications</i> , 2017 , 263, 19-22	1.6	8
182	Structural and optical properties of the recently synthesized (Zr ₃ Ti x)AlC ₂ MAX phases. <i>Journal of Materials Science: Materials in Electronics</i> , 2017 , 28, 3386-3393	2.1	19
181	Gold and silver diffusion in germanium: a thermodynamic approach. <i>Journal of Materials Science: Materials in Electronics</i> , 2017 , 28, 1966-1970	2.1	3
180	Hydrogen and nitrogen codoping of anatase TiO for efficiency enhancement in organic solar cells. <i>Scientific Reports</i> , 2017 , 7, 17839	4.9	18
179	In situ trap properties in CCDs: the donor level of the silicon divacancy. <i>Journal of Instrumentation</i> , 2017 , 12, P01025-P01025	1	6
178	Toward Defect Engineering Strategies to Optimize Energy and Electronic Materials. <i>Applied Sciences (Switzerland)</i> , 2017 , 7, 674	2.6	11
177	Relaxation of the electric resistance in YBa ₂ Cu ₃ O ₇ single crystals at room temperature. <i>Modern Physics Letters B</i> , 2017 , 31, 1750179	1.6	
176	Fluctuation conductivity and possible pseudogap state in FeAs-based superconductor EuFeAsO _{0.85} F _{0.15} . <i>Materials Research Express</i> , 2016 , 3, 076001	1.7	14

175	Oxygen self-diffusion in ThO ₂ under pressure: connecting point defect parameters with bulk properties. <i>Materials Research Express</i> , 2016 , 3, 065501	1.7	2
174	Physical properties of the recently discovered Zr ₂ (Al _{1-x} Bi _x)C MAX phases. <i>Journal of Materials Science: Materials in Electronics</i> , 2016 , 27, 11925-11933	2.1	45
173	Investigation of oxygen self-diffusion in PuO ₂ by combining molecular dynamics with thermodynamic calculations. <i>RSC Advances</i> , 2016 , 6, 103641-103649	3.7	5
172	Infrared studies of the evolution of the CiOi(Sil) defect in irradiated Si upon isothermal anneals. <i>Journal of Applied Physics</i> , 2016 , 119, 125704	2.5	7
171	CO ₂ capture by Li-functionalized silicene. <i>Physica Status Solidi - Rapid Research Letters</i> , 2016 , 10, 458-461	2.5	2
170	Modification of superconducting and resistive properties of HoBa ₂ Cu ₃ O _{7-δ} single crystals under application-removal of high hydrostatic pressure. <i>Modern Physics Letters B</i> , 2016 , 30, 1650188	1.6	16
169	Relative concentrations of carbon related defects in silicon. <i>Journal of Materials Science: Materials in Electronics</i> , 2016 , 27, 11268-11272	2.1	1
168	Controlling A-center concentration in silicon through isovalent doping: mass action analysis. <i>Journal of Materials Science: Materials in Electronics</i> , 2016 , 27, 4385-4391	2.1	3
167	Silicene/germanene on MgX ₂ (X = Cl, Br, and I) for Li-ion battery applications. <i>Nanoscale</i> , 2016 , 8, 7272-7277	7.7	36
166	Attempts to synthesise quaternary MAX phases (Zr,M) ₂ AlC and Zr ₂ (Al,A)C as a way to approach Zr ₂ AlC. <i>Materials Research Letters</i> , 2016 , 4, 137-144	7.4	54
165	Infrared study of defects in nitrogen-doped electron irradiated silicon. <i>Journal of Materials Science: Materials in Electronics</i> , 2016 , 27, 2054-2061	2.1	5
164	Synthesis and DFT investigation of new bismuth-containing MAX phases. <i>Scientific Reports</i> , 2016 , 6, 188209	2.9	82
163	Activation volumes of oxygen self-diffusion in fluorite structured oxides. <i>Materials Research Express</i> , 2016 , 3, 105504	1.7	2
162	Connecting point defect parameters with bulk properties to describe diffusion in solids. <i>Applied Physics Reviews</i> , 2016 , 3, 041304	17.3	23
161	A thermodynamic approach of self- and hetero-diffusion in GaAs: connecting point defect parameters with bulk properties. <i>RSC Advances</i> , 2016 , 6, 53324-53330	3.7	22
160	S-functionalized MXenes as electrode materials for Li-ion batteries. <i>Applied Materials Today</i> , 2016 , 5, 19-24	6.6	64
159	A thermodynamic approach to self-diffusion in silicon: Evidence of a single diffusion mechanism?. <i>Materials Chemistry and Physics</i> , 2016 , 181, 204-208	4.4	17
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